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- **Member of the Texas Instruments** Widebus™ Family
- **EPIC™** (Enhanced-Performance Implanted **CMOS) Submicron Process**
- All Outputs Have Equivalent 26- Ω Series Resistors, So No External Resistors Are Required
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per **JESD 17**
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- **Package Options Include Plastic Thin** Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV), and 300-mil Shrink Small-Outline (DL) Packages

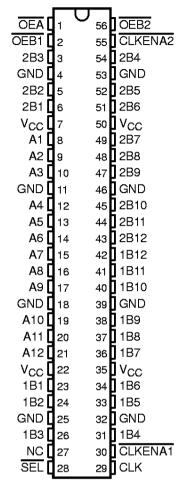
description

This 12-bit to 24-bit registered bus exchanger is designed for 2.3-V to 3.6-V V_{CC} operation.

The SN74ALVCHR162269A is used applications in which two separate ports must be multiplexed onto, or demultiplexed from, a single port. It is particularly suitable as an interface between synchronous DRAMs and high-speed microprocessors.

Data is stored in the internal B-port registers on the low-to-high transition of the clock (CLK) input when the appropriate clock-enable (CLKENA)

DGG, DGV, OR DL PACKAGE (TOP VIEW)



NC - No internal connection

inputs are low. Proper control of these inputs allows two sequential 12-bit words to be presented as a 24-bit word on the B port. For data transfer in the B-to-A direction, a single storage register is provided. The select (SEL) line selects 1B or 2B data for the A outputs. The register on the A output permits the fastest possible data transfer, thus extending the period during which the data is valid on the bus. The control terminals are registered so that all transactions are synchronous with CLK. Data flow is controlled by the active-low output enables (OEA, OEB1, and OEB2).

To ensure the high-impedance state during power up or power down, a clock pulse should be applied as soon as possible and OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. Due to OE being routed through a register, the active state of the outputs cannot be determined prior to the arrival of the first clock pulse.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.



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description (continued)

All outputs are designed to sink up to 12 mA and include equivalent 26- Ω resistors to reduce overshoot and undershoot.

The SN74ALVCHR162269A is characterized for operation from -40°C to 85°C.

Function Tables

OUTPUT ENABLE

INPUTS			OUTPUTS		
CLK	OEA	OEB	Α	1B, 2B	
\uparrow	Н	Н	Z	Z	
↑	Н	L	z	Active	
↑	L	Н	Active	Z	
↑	L	L	Active	Active	

A-TO-B STORAGE (OEB = L)

	INPUTS			OUTI	PUTS
CLKENA1	CLKENA2	CLK	Α	1B	2B
L	Н	↑	٦	L	2B ₀ †
L	Н	\uparrow	Н	Н	2B ₀ †
L	L	\uparrow	L	L	L
L	L	\uparrow	Н	Н	Н
Н	L	\uparrow	L	1B ₀ †	L
Н	L	\uparrow	Н	1B ₀ †	Н
Н	Н	Χ	Χ	1B ₀ †	2B ₀ †

[†]Output level before the indicated steady-state input conditions were established

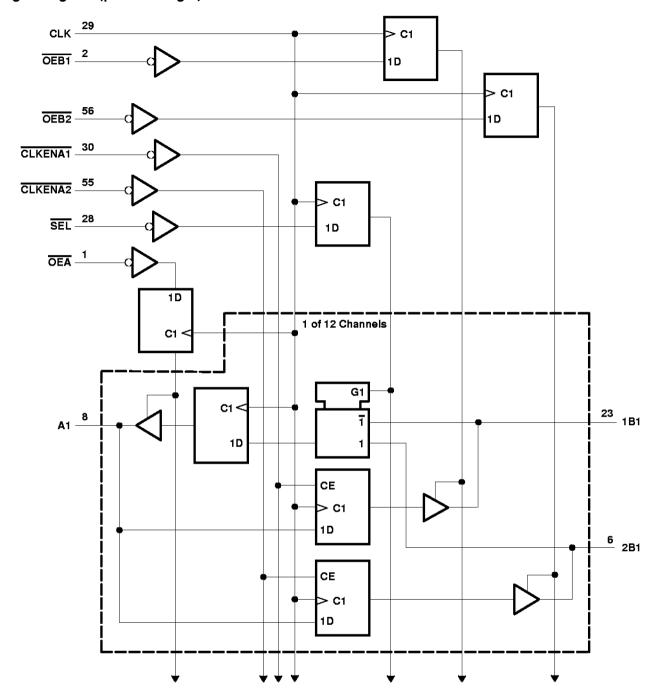
B-TO-A STORAGE (OEA = L)

	INPL	OUTPUT		
CLK	SEL	1B	2B	A
Х	Н	Х	Х	A ₀ †
Х	L	Χ	Χ	A ₀ † A ₀ †
↑	Н	L	X	L
↑	Н	Н	X	Н
↑	L	Χ	L	L
↑	L	X	Н	Н

[†] Output level before the indicated steady-state input conditions were established



logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range, V _{CC}		0.5 V to 4.6 V
Input voltage range, V _I : Except I/O ports (see I		
I/O ports (see Notes 1	and 2)	0.5 V to V _{CC} + 0.5 V
Output voltage range, V _O (see Notes 1 and 2)		$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{ K }(V_{ } < 0)$		
Output clamp current, I _{OK} (V _O < 0)		
Continuous output current, IO		±50 mA
Continuous current through each V _{CC} or GND		±100 mA
Package thermal impedance, θ _{JA} (see Note 3):	DGG package	81°C/W
	DGV package	86°C/W
	DL package	74°C/W
Storage temperature range, T _{sto}	·	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. This value is limited to 4.6 V maximum.
 - 3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

			MIN	MAX	UNIT
Vcc	Supply voltage		2.3	3.6	٧
V _{IH} H	V _{CC} = 2.3 V to 2.7 V		1.7		V
	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		, v
V _{IL}	Less level innut vallen	V _{CC} = 2.3 V to 2.7 V		0.7	V
	Low-level input voltage $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$			8.0	ľ
V _I	Input voltage	•	0	Vcc	٧
٧o	Output voltage		0	Vcc	٧
		V _{CC} = 2.3 V		ф	
IОН	High-level output current	V _{CC} = 2.7 V		-8	mA
		V _{CC} = 3 V		-12	
		V _{CC} = 2.3 V		6	
loL	Low-level output current	V _{CC} = 2.7 V		8	mA
		V _{CC} = 3 V		12	
Δt/Δν	Input transition rise or fall rate		0	10	ns/V
Τ _A	Operating free-air temperature		-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER	TEST C	ONDITIONS	vcc	MIN	TYPT	MAX	UNIT	
		I _{OH} = -100 μA		2.3 V to 3.6 V	V _{CC} -0	.2			
		I _{OH} = -4 mA	V _{IH} = 1.7 V	2.3 V	1.9				
		10H = -4 IIIA	V _{IH} = 2 V	2.7 V	2.2				
VOH	I _{OH} = -6 mA	V _{IH} = 1.7 V	2.3 V	1.7			V		
		IOH = -0 IIIA	V _{IH} = 2 V	3 V	2.4				
	$I_{OH} = -8 \text{ mA},$	V _{IH} = 2 V	2.7 V	2					
		$I_{OH} = -12 \text{ mA},$	V _{IH} = 2 V	3 V	2				
		I _{OL} = 100 μA		2.3 V to 3.6 V			0.2		
		I _{OL} = 4 mA	V _{IL} = 0.7 V	2.3 V			0.4		
	IOL = 4 MA	V _{IL} = 0.8 V	2.7 V			0.4	.4		
VOL		le. 6 mA	V _{IL} = 0.7 V	2.3 V			0.55	٧	
	I _{OL} = 6 mA	V _{IL} = 0.8 V	3 V			0.55	-		
	$I_{OL} = 8 \text{ mA},$	V _{IL} = 0.8 V	2.7 V			0.6			
		$I_{OL} = 12 \text{ mA},$ $V_{IL} = 0.8 \text{ V}$		3 V			8.0		
lį		V _I = V _{CC} or GND		3.6 V			±5	μΑ	
		V _I = 0.7 V		2.3 V	45				
		V _I = 1.7 V		2.5 V	-45				
l(hold)	VOL II II(hold) IOZ ICC AICC Ci Control inputs	V _I = 0.8 V		3 V	75			μΑ	
l(hold)		V _I = 2 V		3 *	-75]	
		$V_1 = 0 \text{ to } 3.6 \text{ V}^{\ddagger}$		3.6 V			±500		
loz§		$V_O = V_{CC}$ or GND		3.6 V			±10	μΑ	
		$V_I = V_{CC}$ or GND,	IO = 0	3.6 V			40	μΑ	
∆lcc		One input at V _{CC} - 0.6 V,	Other inputs at V _{CC} or GND	3 V to 3.6 V			750	μΑ	
	Control inputs	V _I = V _{CC} or GND		3.3 V		5		рF	
C _{io}	A or B ports	$V_O = V_{CC}$ or GND		3.3 V		8.5		рF	

[†] All typical values are at V_{CC} = 3.3 V, T_A = 25°C. ‡This is the bus-hold maximum dynamic current required to switch the input from one state to another.

 $[\]mbox{\ensuremath{\$}}\mbox{ For I/O ports, the parameter I}_{\mbox{\ensuremath{OZ}}}\mbox{ includes the input leakage current.}$

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 and 2)

			VCC =		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.15 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
fclock	Clock freque	псу		95		115		135		135	MHz
t _w	Pulse duration	on, CLK high or low	5.2		4.3		3.3		3.3		ns
		A data before CLK↑	1.4		1.4		0.9		1		
	Setup time	B data before CLK↑	1.6		1.5		1		1.1		
t _{su}		SEL before CLK↑	0.8		1.1		1.3		1.3		ns
^ı su		CLKENA1 or CLKENA2 before CLK↑	0.8		1		0.7		0.8		
		OE before CLK↑	1.7		1.6		1.1		1.2		
		A data after CLK↑	0.9		0.9		1.1		1.2		
		B data after CLK↑	0.8		0.6		0.8		1		
th	Hold time	SEL after CLK↑	1.1		0.8		1.6		1.7		ns
		CLKENA1 or CLKENA2 after CLK↑	1.4		1		1.4		1.6		
		OE after CLK↑	0.9	·	0.8	·	1		1.2	·	

switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 and 2)

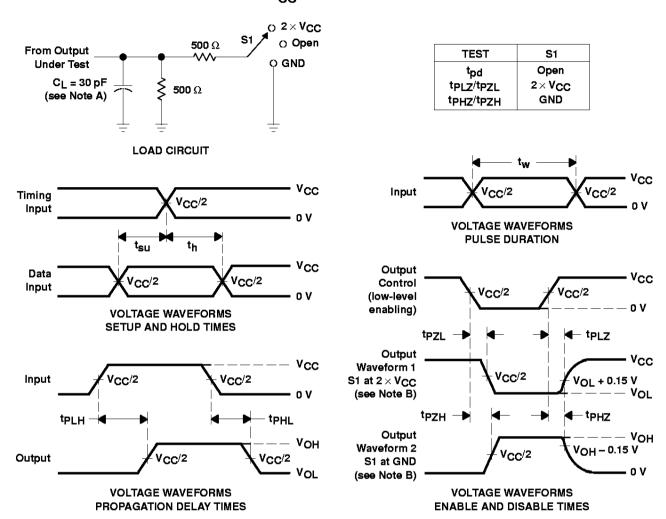
PARAMETER	FROM (INPUT)			V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.15 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
		(0011 01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
f _{max}			95		115		135		135		MHz	
	CLK	В	1.8	7.1		6.9	2.3	5.6	2.2	5.8	ns	
^t pd		Α	1.4	5.8		5.8	2	5	2	5.2	115	
	CLK	В	2.4	7.2		6.9	2.3	5.6	2.3	5.8	20	
^t en		Α	2.1	6.2		6	2.1	5.2	2.1	5.3	ns	
[†] dis	CLK	В	2.6	7.9		6.7	2.3	5.8	2.4	6	ns	
		Α	2	7.8		6.2	2.2	5.9	2.1	6	10	

operating characteristics, T_A = 25°C

PARAMETER			TEST CONDITIONS		V _{CC} = 2.5 V ± 0.2 V	V _{CC} = 3.3 V ± 0.15 V	UNIT
	Power dissipation capacitance	All outputs enabled	0. 0	f 10 MIL	142	172	pF
C _{pd}	per exchanger	All outputs disabled	C _L = 0,	f = 10 MHz	115	129	рг



PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



NOTES: A. CL includes probe and jig capacitance.

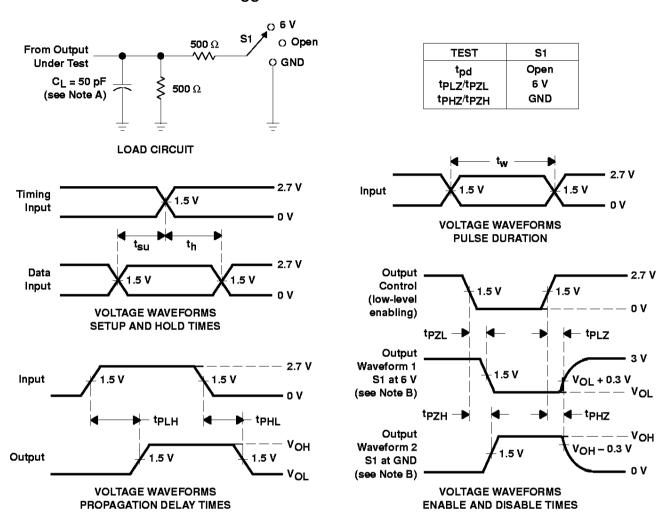
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2 ns. $t_f \leq$ 2 ns.
- The outputs are measured one at a time with one transition per measurement.
- E. tpl 7 and tpH7 are the same as tdis-
- F. tpzL and tpzH are the same as ten.
- G. tpl H and tpHI are the same as tod.

Figure 1. Load Circuit and Voltage Waveforms



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PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.7 V AND 3.3 V \pm 0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLZ and tpHZ are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tplH and tpHL are the same as tod.

Figure 2. Load Circuit and Voltage Waveforms



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